# 2SB1414

## Silicon PNP epitaxial planar type

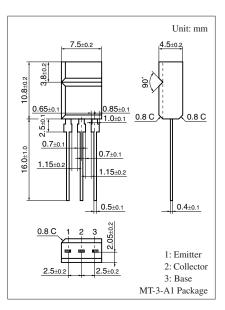
For low-frequency driver/high power amplification Complementary to 2SD2134

#### Features

- $\bullet$  Excellent current  $I_C$  characteristics of forward current transfer ratio  $h_{FE} \mbox{ vs. collector}$
- $\bullet$  High transition frequency  $f_{\rm T}$
- Allowing automatic insertion with radial taping

### Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit			
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	-150	V			
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	-150	V			
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	-5	V			
Collector current	I <sub>C</sub>	-1	А			
Peak collector current	I <sub>CP</sub>	-1.5	А			
Collector power dissipation	P <sub>C</sub>	1.5	W			
Junction temperature	Tj	150	°C			
Storage temperature	T <sub>stg</sub>	-55 to +150	°C			



#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{C} = -100 \ \mu A, \ I_{B} = 0$	-150			V
Emiter-base voltage (Collector open)	V <sub>EBO</sub>	$I_E = -10 \ \mu A, \ I_C = 0$	-5			V
Forward current transfer ratio *1	h <sub>FE1</sub> *2	$V_{CE} = -10 \text{ V}, I_C = -150 \text{ mA}$	90		330	
	h <sub>FE2</sub>	$V_{CE} = -5 \text{ V}, I_C = -500 \text{ mA}$	50			
Collector-emitter saturation voltage *1	V <sub>CE(sat)</sub>	$I_{\rm C} = -500 \text{ mA}, I_{\rm B} = -50 \text{ mA}$		- 0.5	-2.0	V
Base-emitter saturation voltage *1	V <sub>BE(sat)</sub>	$I_{\rm C} = -500 \text{ mA}, I_{\rm B} = -50 \text{ mA}$		-1.0	-2.0	V
Transition frequency	f <sub>T</sub>	$V_{CB} = -10 \text{ V}, I_E = 50 \text{ mA}, f = 200 \text{ MHz}$		200		MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		30		pF
(Common base, input open circuited)						

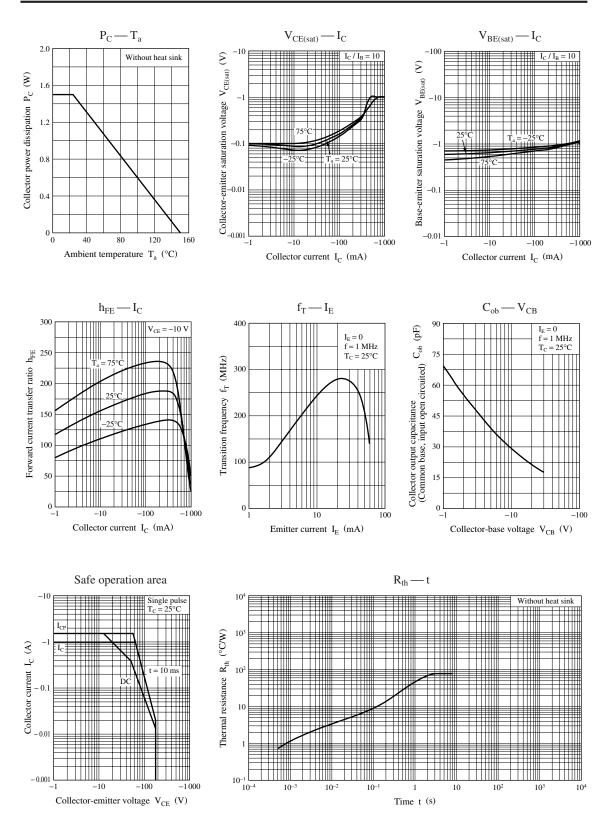
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*1: Pulse measurement

\*2: Rank classification

Rank	Q	R	S	
h <sub>FE1</sub>	90 to 155	130 to 220	185 to 330	

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